

MC74HC1G04

Single Inverter

The MC74HC1G04 is a high speed CMOS inverter fabricated with silicon gate CMOS technology.

The internal circuit is composed of multiple stages, including a buffer output which provides high noise immunity and stable output.

The MC74HC1G04 output drive current is 1/2 compared to MC74HC series.

- High Speed: $t_{PD} = 7 \text{ ns}$ (Typ) at $V_{CC} = 5 \text{ V}$
- Low Power Dissipation: $I_{CC} = 1 \mu\text{A}$ (Max) at $T_A = 25^\circ\text{C}$
- High Noise Immunity
- Balanced Propagation Delays ($t_{PLH} = t_{PHL}$)
- Symmetrical Output Impedance ($I_{OH} = I_{OL} = 2 \text{ mA}$)
- Chip Complexity: FET = 105
- Pb-Free Packages are Available

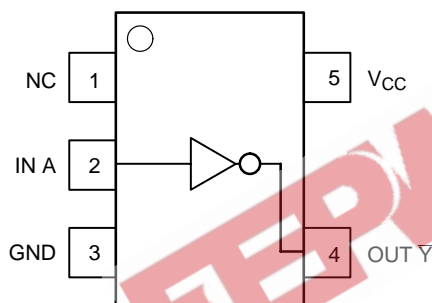


Figure 1. Pinout (Top View)

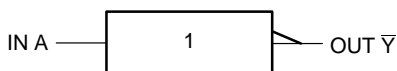


Figure 2. Logic Symbol



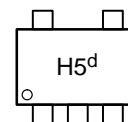
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MARKING DIAGRAMS



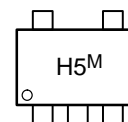
SC70-5/SC-88A/SOT-353
DF SUFFIX
CASE 419A



Pin 1



SOT23-5/TSOP-5/SC59-5
DT SUFFIX
CASE 483



Pin 1

d = Date Code
M = Month Code

PIN ASSIGNMENT

| PIN ASSIGNMENT | |
|----------------|---------------|
| 1 | NC |
| 2 | IN A |
| 3 | GND |
| 4 | OUT \bar{Y} |
| 5 | V_{CC} |

FUNCTION TABLE

| Input A | Output \bar{Y} |
|---------|------------------|
| L | H |
| H | L |

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

MC74HC1G04

MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|----------------------|---|--|----------------------|
| V _{CC} | DC Supply Voltage | - 0.5 to +7.0 | V |
| V _{IN} | DC Input Voltage | -0.5 to V _{CC} +0.5 | V |
| V _{OUT} | DC Output Voltage | -0.5 to V _{CC} +0.5 | V |
| I _{IK} | DC Input Diode Current | ±20 | mA |
| I _{OK} | DC Output Diode Current | ±20 | mA |
| I _{OUT} | DC Output Sink Current | ±12.5 | mA |
| I _{CC} | DC Supply Current per Supply Pin | ±25 | mA |
| T _{STG} | Storage Temperature Range | - 65 to +150 | °C |
| T _L | Lead Temperature, 1 mm from Case for 10 Seconds | 260 | °C |
| T _J | Junction Temperature Under Bias | +150 | °C |
| θ _{JA} | Thermal Resistance | SC70-5/SC-88A (Note 1) TSOP-5 350 230 | °C/W |
| P _D | Power Dissipation in Still Air at 85°C | SC70-5/SC-88A TSOP-5 150 200 | mW |
| MSL | Moisture Sensitivity | Level 1 | |
| F _R | Flammability Rating | Oxygen Index: 28 to 34 | UL 94 V-0 @ 0.125 in |
| V _{ESD} | ESD Withstand Voltage | Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4) | >2000 >200 N/A |
| I _{LATCHUP} | Latchup Performance | Above V _{CC} and Below GND at 125°C (Note 5) | ±500 mA |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace with no air flow.
2. Tested to EIA/JESD22-A114-A.
3. Tested to EIA/JESD22-A115-A.
4. Tested to JESD22-C101-A.
5. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Max | Unit |
|---------------------------------|-----------------------------|--|--------------------------------|------|
| V _{CC} | DC Supply Voltage | 2.0 | 6.0 | V |
| V _{IN} | DC Input Voltage | 0.0 | V _{CC} | V |
| V _{OUT} | DC Output Voltage | 0.0 | V _{CC} | V |
| T _A | Operating Temperature Range | -55 | +125 | °C |
| t _r , t _f | Input Rise and Fall Time | V _{CC} = 2.0 V V _{CC} = 3.0 V V _{CC} = 4.5 V V _{CC} = 6.0 V | 0 1000 600 500 400 | ns |

DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

| Junction Temperature °C | Time, Hours | Time, Years |
|-------------------------|-------------|-------------|
| 80 | 1,032,200 | 117.8 |
| 90 | 419,300 | 47.9 |
| 100 | 178,700 | 20.4 |
| 110 | 79,600 | 9.4 |
| 120 | 37,000 | 4.2 |
| 130 | 17,800 | 2.0 |
| 140 | 8,900 | 1.0 |

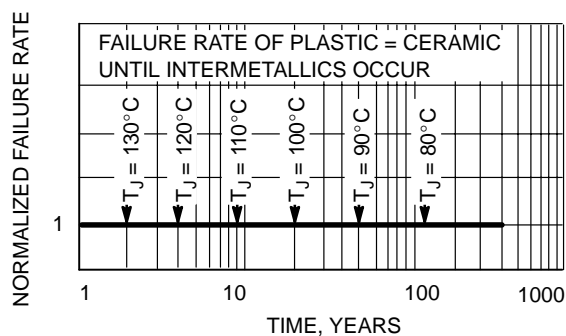


Figure 3. Failure Rate vs. Time Junction Temperature

MC74HC1G04

DC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Test Conditions | V _{CC} (V) | T _A = 25°C | | | T _A ≤ 85°C | | -55°C ≤ T _A ≤ 125°C | | Unit |
|-----------------|---|--|--------------------------|----------------------------|--------------------------|----------------------------|----------------------------|----------------------------|--------------------------------|----------------------------|------|
| | | | | Min | Typ | Max | Min | Max | Min | Max | |
| V _{IH} | Minimum High-Level Input Voltage | | 2.0 3.0 4.5 6.0 | 1.5 2.1 3.15 4.20 | | | 1.5 2.1 3.15 4.20 | | 1.5 2.1 3.15 4.20 | V | |
| V _{IL} | Maximum Low-Level Input Voltage | | 2.0 3.0 4.5 6.0 | | | 0.5 0.9 1.35 1.80 | | 0.5 0.9 1.35 1.80 | | 0.5 0.9 1.35 1.80 | V |
| V _{OH} | Minimum High-Level Output Voltage V _{IN} = V _{IH} or V _{IL} | V _{IN} = V _{IH} or V _{IL} I _{OH} = -20 μA | 2.0 3.0 4.5 6.0 | 1.9 2.9 4.4 5.9 | 2.0 3.0 4.5 6.0 | | 1.9 2.9 4.4 5.9 | | 1.9 2.9 4.4 5.9 | V | |
| | | V _{IN} = V _{IH} or V _{IL} I _{OH} = -2 mA I _{OH} = -2.6 mA | 4.5 6.0 | 4.18 5.68 | 4.31 5.80 | | 4.13 5.63 | | 4.08 5.58 | | |
| V _{OL} | Maximum Low-Level Output Voltage V _{IN} = V _{IH} or V _{IL} | V _{IN} = V _{IH} or V _{IL} I _{OL} = 20 μA | 2.0 3.0 4.5 6.0 | | 0.0 0.0 0.0 0.0 | 0.1 0.1 0.1 0.1 | | 0.1 0.1 0.1 0.1 | | 0.1 0.1 0.1 0.1 | V |
| | | V _{IN} = V _{IH} or V _{IL} I _{OL} = 2 mA I _{OL} = 2.6 mA | 4.5 6.0 | | 0.17 0.18 | 0.26 0.26 | | 0.33 0.33 | | 0.40 0.40 | |
| I _{IN} | Maximum Input Leakage Current | V _{IN} = 6.0 V or GND | 6.0 | | | ±0.1 | | ±1.0 | | ±1.0 | μA |
| I _{CC} | Maximum Quiescent Supply Current | V _{IN} = V _{CC} or GND | 6.0 | | | 1.0 | | 10 | | 40 | μA |

AC ELECTRICAL CHARACTERISTICS (Input t_r = t_f = 6.0 ns)

| Symbol | Parameter | Test Conditions | T _A = 25°C | | | T _A ≤ 85°C | | -55°C ≤ T _A ≤ 125°C | | Unit |
|--|---|--|-----------------------|---------|----------|-----------------------|----------|--------------------------------|----------|------|
| | | | Min | Typ | Max | Min | Max | Min | Max | |
| t _{PLH} , t _{PHL} | Maximum Propagation Delay, Input A or B to Y | V _{CC} = 5.0 V C _L = 15 pF | | 3.5 | 15 | | 20 | | 25 | ns |
| | | V _{CC} = 2.0 V C _L = 50 pF | | 18 | 100 | | 125 | | 155 | |
| | | V _{CC} = 3.0 V | | 10 | 27 | | 35 | | 90 | |
| | | V _{CC} = 4.5 V V _{CC} = 6.0 V | | 7 6 | 20 17 | | 25 21 | | 35 26 | |
| t _{TLH} , t _{THL} | Output Transition Time | V _{CC} = 5.0 V C _L = 15 pF | | 3 | 10 | | 15 | | 20 | ns |
| | | V _{CC} = 2.0 V C _L = 50 pF | | 25 | 125 | | 155 | | 200 | |
| | | V _{CC} = 3.0 V | | 16 | 35 | | 45 | | 60 | |
| | | V _{CC} = 4.5 V V _{CC} = 6.0 V | | 11 9 | 25 21 | | 31 26 | | 38 32 | |
| C _{IN} | Maximum Input Capacitance | | | 5 | 10 | | 10 | | 10 | pF |

| | | | | |
|-----------------|--|---|--|----|
| C _{PD} | Power Dissipation Capacitance (Note 6) | Typical @ 25°C, V _{CC} = 5.0 V | | pF |
| | | 10 | | |

6. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no-load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

MC74HC1G04

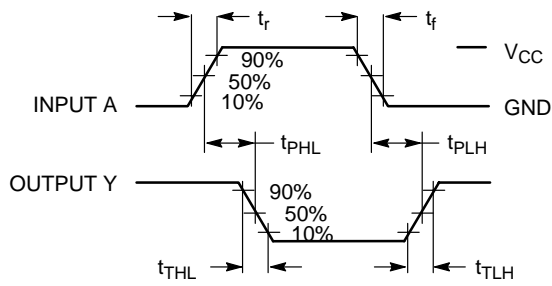
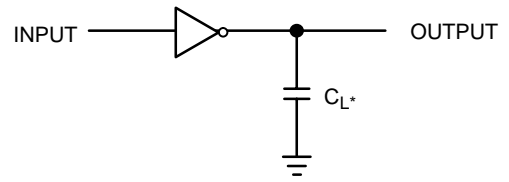


Figure 4. Switching Waveforms



*Includes all probe and jig capacitance.
A 1-MHz square input wave is recommended for propagation delay tests.

Figure 5. Test Circuit

DEVICE ORDERING INFORMATION

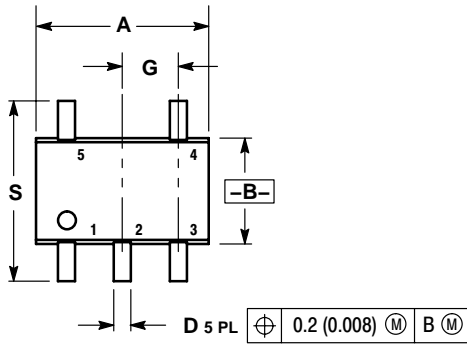
| Device Order Number | Device Nomenclature | | | | | | Package Type | Tape and Reel Size† |
|---------------------|-------------------------|-----------------------|------------|-----------------|----------------|----------------------|---------------------------------|-------------------------|
| | Logic Circuit Indicator | Temp Range Identifier | Technology | Device Function | Package Suffix | Tape and Reel Suffix | | |
| MC74HC1G04DFT1 | MC | 74 | HC1G | 08 | DF | T1 | SC70-5/SC-88A/SOT-353 | 178 mm (7 in) 3000 Unit |
| MC74HC1G04DFT1G | MC | 74 | HC1G | 08 | DF | T1 | SC70-5/SC-88A/SOT-353 (Pb-Free) | 178 mm (7 in) 3000 Unit |
| MC74HC1G04DFT2 | MC | 74 | HC1G | 08 | DF | T2 | SC70-5/SC-88A/SOT-353 | 178 mm (7 in) 3000 Unit |
| MC74HC1G04DFT2G | MC | 74 | HC1G | 08 | DF | T2 | SC70-5/SC-88A/SOT-353 (Pb-Free) | 178 mm (7 in) 3000 Unit |
| MC74HC1G04DTT1 | MC | 74 | HC1G | 08 | DT | T1 | SOT23-5/TSOP-5/SC59-5 | 178 mm (7 in) 3000 Unit |
| MC74HC1G04DTT1G | MC | 74 | HC1G | 08 | DT | T1 | SOT23-5/TSOP-5/SC59-5 (Pb-Free) | 178 mm (7 in) 3000 Unit |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MC74HC1G04

PACKAGE DIMENSIONS

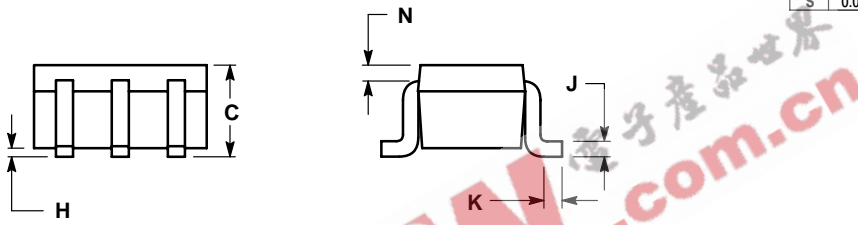
SC70-5/SC-88A/SOT-353
 DF SUFFIX
 5-LEAD PACKAGE
 CASE 419A-02
 ISSUE G



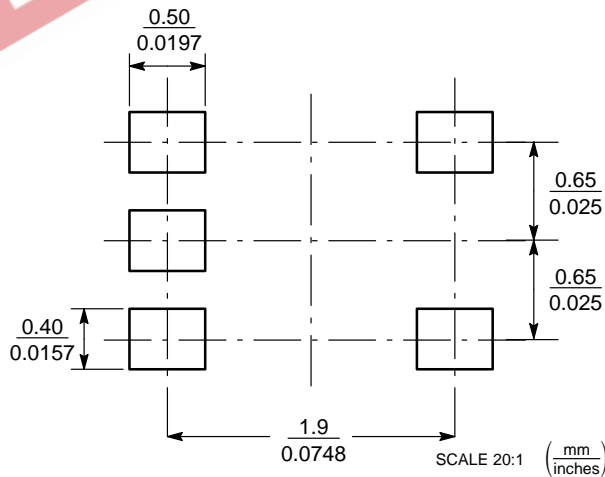
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| DIM | INCHES | | MILLIMETERS | |
|-----|-----------|-------|-------------|------|
| | MIN | MAX | MIN | MAX |
| A | 0.071 | 0.087 | 1.80 | 2.20 |
| B | 0.045 | 0.053 | 1.15 | 1.35 |
| C | 0.031 | 0.043 | 0.80 | 1.10 |
| D | 0.004 | 0.012 | 0.10 | 0.30 |
| G | 0.026 BSC | | 0.65 BSC | |
| H | --- | 0.004 | --- | 0.10 |
| J | 0.004 | 0.010 | 0.10 | 0.25 |
| K | 0.004 | 0.012 | 0.10 | 0.30 |
| N | 0.008 REF | | 0.20 REF | |
| S | 0.079 | 0.087 | 2.00 | 2.20 |



SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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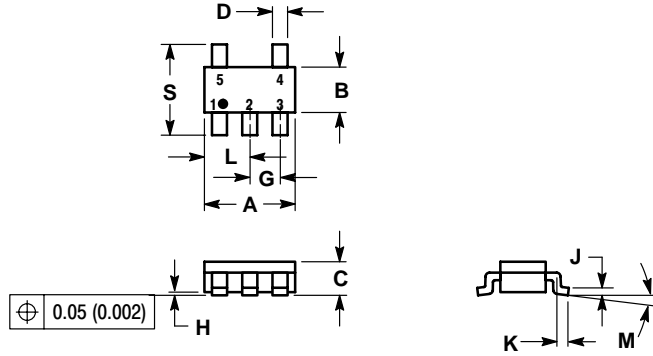
PACKAGE DIMENSIONS

SOT23-5/TSOP-5/SC59-5

DT SUFFIX
5-LEAD PACKAGE
CASE 483-02
ISSUE C

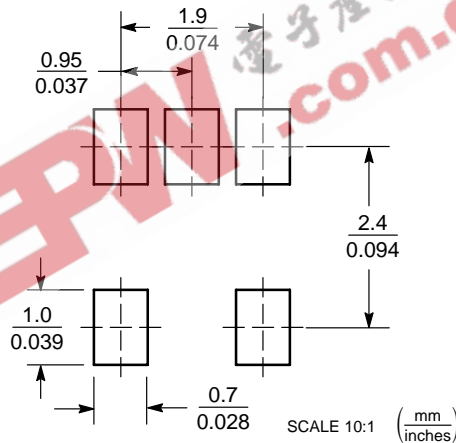
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. A AND B DIMENSIONS DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.




| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|-------|--------|--------|
| | MIN | MAX | MIN | MAX |
| A | 2.90 | 3.10 | 0.1142 | 0.1220 |
| B | 1.30 | 1.70 | 0.0512 | 0.0669 |
| C | 0.90 | 1.10 | 0.0354 | 0.0433 |
| D | 0.25 | 0.50 | 0.0098 | 0.0197 |
| G | 0.85 | 1.05 | 0.0335 | 0.0413 |
| H | 0.013 | 0.100 | 0.0005 | 0.0040 |
| J | 0.10 | 0.26 | 0.0040 | 0.0102 |
| K | 0.20 | 0.60 | 0.0079 | 0.0236 |
| L | 1.25 | 1.55 | 0.0493 | 0.0610 |
| M | 0 | 10 | 0 | 10 |
| S | 2.50 | 3.00 | 0.0985 | 0.1181 |

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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